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|  | <h2>SI9410BDY-T1-E3</h2> |
| | <p>Hersteller-Teilenummer: SI9410BDY-T1-E3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 30V 6.2A 8SOIC</p> <p>Datenblätter:  SI9410BDY-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 55407 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
| <p>Image may be representation. See specs for product details.</p> | |

Spezifikationen

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| Teilenummer | SI9410BDY-T1-E3 |
| Hersteller | Vishay / Siliconix |
| Beschreibung | MOSFET N-CH 30V 6.2A 8SOIC |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus | 55407 pcs Stock |
| Serie | TrenchFET® |
| Technologie | MOSFET (Metal Oxide) |
| Betriebstemperatur | -55°C ~ 150°C (TJ) |
| Befestigungsart | Surface Mount |
| Verpackung / Gehäuse | 8-SOIC (0.154", 3.90mm Width) |
| Supplier Device-Gehäuse | 8-SO |
| Verlustleistung (max) | 1.5W (Ta) |
| Typ FET | N-Channel |
| FET-Merkmal | - |
| Drain-Source-Spannung (Vdss) | 30V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 6.2A (Ta) |
| Rds On (Max) @ Id, Vgs | 24 mOhm @ 8.1A, 10V |
| VGS (th) (Max) @ Id | 3V @ 250µA |
| Gate Charge (Qg) (Max) @ Vgs | 23nC @ 10V |
| Eingabekapazität (Ciss) (Max) @ Vds | - |
| Verpackung | Tape & Reel (TR) |





























SI9410BDY-T1-E3 ist neu im Original, Suche SI9410BDY-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI9410BDY-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI9410BDY-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

| | | | |
|---|---|--|--|
|  <p>SI9410ADY-T1-E3 VISHAY SI9410ADY-T1-E3 VISHAY</p> |  <p>SI9410BDY-T1-E3. VISHAY SI9410BDY-T1-E3. VISHAY</p> |  <p>SI9410DY VIS SI9410DY VIS</p> |  <p>SI9410BDY VIS SI9410BDY VIS</p> |
|  <p>SI9410ADY-T1-GE3 VISHAY SI9410ADY-T1-GE3 VISHAY</p> |  <p>SI9410BDY-T1 VISHAY SI9410BDY-T1 VISHAY</p> |  <p>SI9410BDY-T1-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 6.2A 8SOIC</p> |  <p>SI9410BDY-T1-GE3 Vishay / Siliconix MOSFET N-CH 30V 6.2A 8SOIC</p> |

heiße Teile

Mehr

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|  SI9243AEY-T1 |  SI9243AEY-T1-E3 |  SI9243AEY-T1-E3 | D SI9400DY |  SI9400DY-T1 |
|  SI9400DY-T1-E3 |  SI9401DB-T1 | D SI9405DY |  SI9405DY-T1 |  SI9405DY-T1-E3 |
|  SI9407ADY |  SI9407ADY-T1-E3 |  SI9407AEY-T1-E3 |  SI9407BDY |  SI9407BDY-T1-E3 |
| D SI9407BDY-T1-E3 |  SI9407BDY-T1-GE3 |  SI9407BDY-T1-GE3 |  SI9407DY |  SI9407DY-T1-E3 |
|  SI9407DY-T1-GE3 |  SI9410ADY-T1-E3 |  SI9410ADY-T1-GE3 |  SI9410BDY |  SI9410BDY-T1-E3 |
|  SI9410BDY-T1-E3. |  SI9410BDY-T1-GE3 | D SI9410BDY-T1-GE3 |  SI9410DY |  SI9410DY-NL |
|  SI9410DY-T1 | D SI9410DY-T1-E3 |  SI9410DY-T1-E3. |  SI9410DY-T1-GE3 |  SI9410DY-TI |
|  SI9420DY |  SI9420DY-T1 |  SI9420DY-T1-E3 |  SI9420DYTI |  SI9422DY-T1-E3 |
|  SI9424ADY-T1-E3 |  SI9424BDY-T1-E3 |  SI9424BDY-T1-E3 | D SI9424BDY-T1-GE3 |  SI9424BDY-T1-GE3 |
|  SI9424DY |  SI9424DY |  SI9424DY-T1 |  SI9424DY-T1-E3 |  SI9424DY-T1-E3. |

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